



CPH6539 — NPN Epitaxial Planar Silicon Transistor

DC / DC Converter Applications

Features

- Small-sized package with two NPN transistors (CPH3215 equivalency) contained in one package
- $V_{CE0}=30V$, $I_C=1.5A$
- Low Collector-to-Emitter Saturation Voltage $V_{CE(sat)}=0.16V(\text{typ.})@I_C=0.75A$
- High-speed switching $t_f=30ns(\text{typ.})@I_C=0.75A$

Specifications

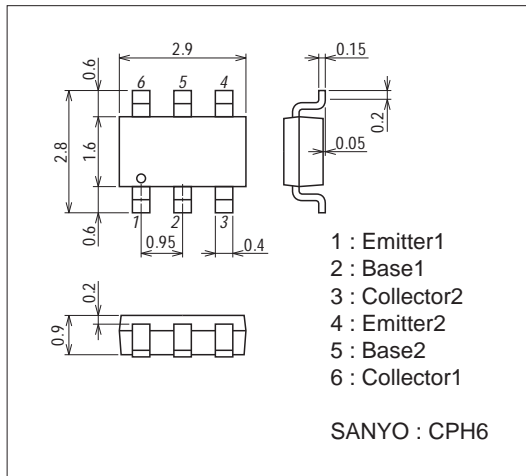
Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		40	V
Collector-to-Emitter Voltage	V_{CEO}		30	V
Emitter-to-Base Voltage	V_{EBO}		5	V
Collector Current	I_C		1.5	A
Collector Current (Pulse)	I_{CP}		3	A
Base Current	I_B		300	mA
Collector Dissipation	P_C	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.9	W
Total Power Dissipation	P_T	When mounted on ceramic substrate (600mm ² ×0.8mm)	1.2	W
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Package Dimensions

unit : mm (typ)

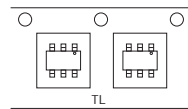
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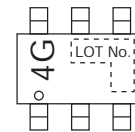
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-96, SC-95, SOT346, SOT457
- Minimum Packing Quantity : 3,000 pcs./reel

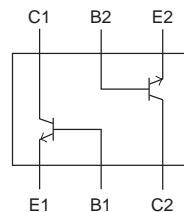
Packing Type: TL



Marking



Electrical Connection

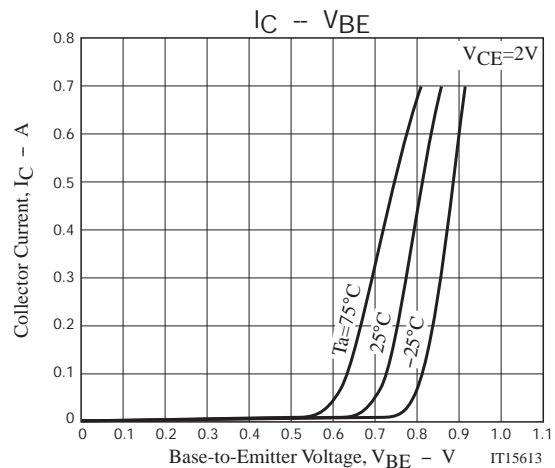
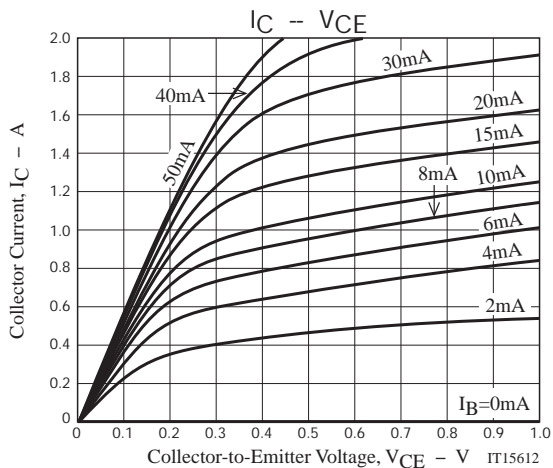
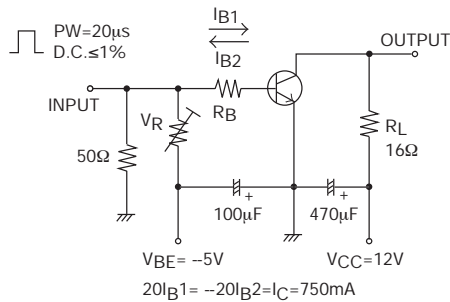


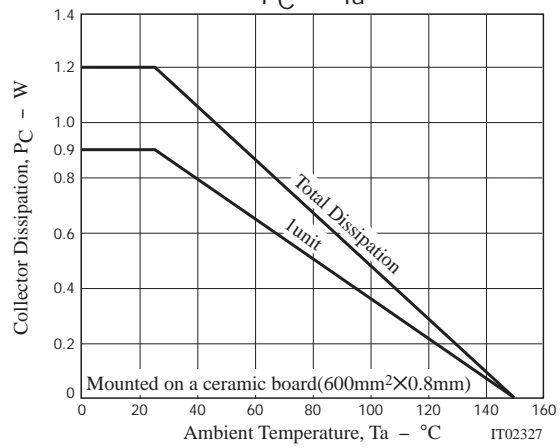
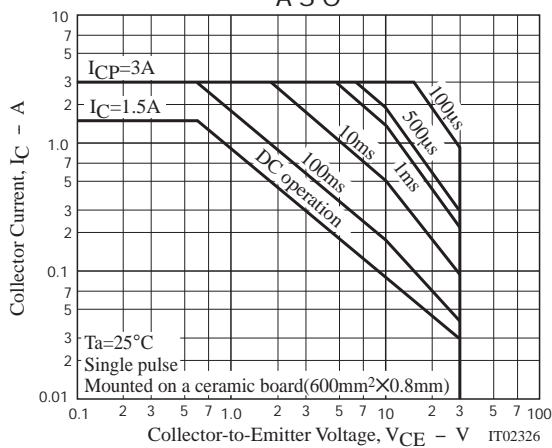
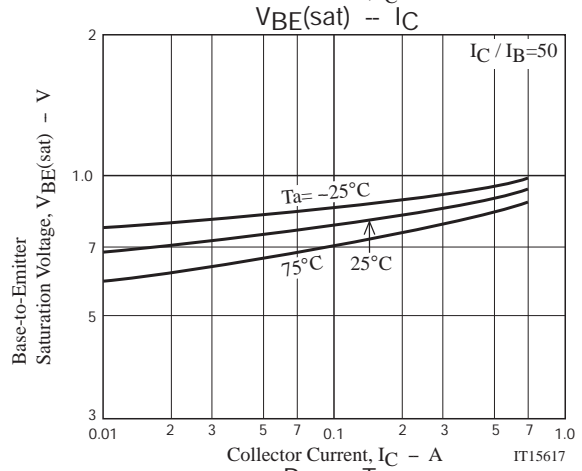
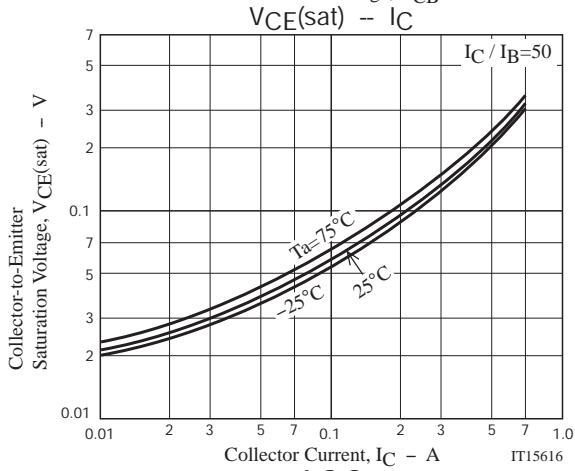
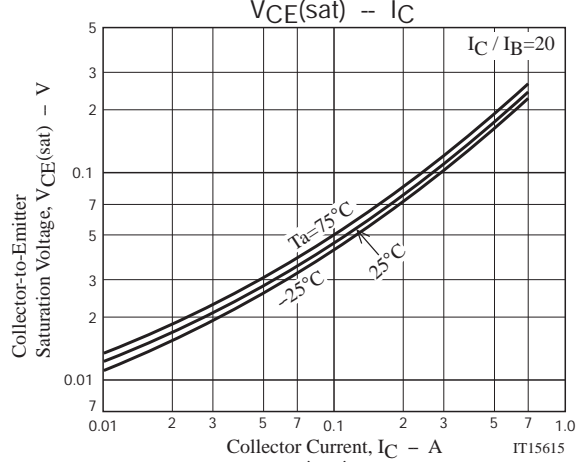
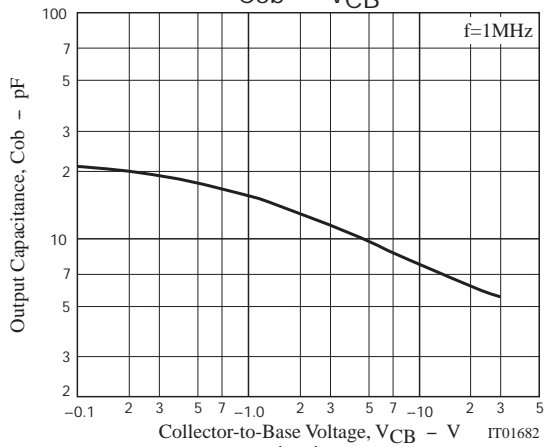
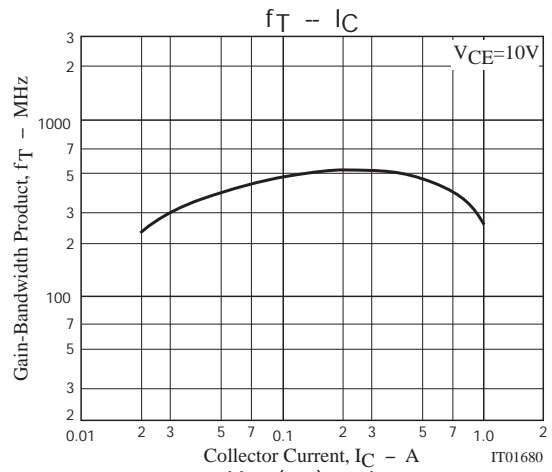
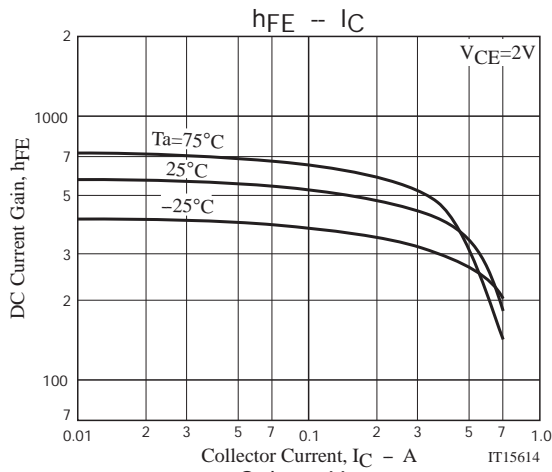
CPH6539

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0\text{A}$			0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=100\text{mA}$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=300\text{mA}$		500		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		8		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=750\text{mA}, I_B=15\text{mA}$		160	250	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=750\text{mA}, I_B=15\text{mA}$		0.85	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0\text{A}$	40			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, R_{BE}=\infty$	30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0\text{A}$	5			V
Turn-On Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}	See specified Test Circuit.		205		ns
Fall Time	t_f	See specified Test Circuit.		30		ns

Switching Time Test Circuit





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